



SSCN5551GS6

High Frequency High Gain NPN Power BJT

➤ Features

VCB	VCE	VEB	IC
180V	160V	6V	600mA

➤ Description

This device is designed for general-purpose high-voltage amplifiers and gas discharge display drivers. It is Ideal for medium power amplification and switching.

➤ Applications

- General-purpose high-voltage amplifiers
- Gas discharge display drivers
- Medium power amplification and switching

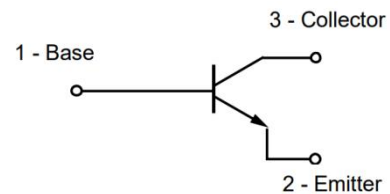
➤ Ordering Information

Device	Package	Shipping
SSCN5551GS6	SOT-23	3000/Reel

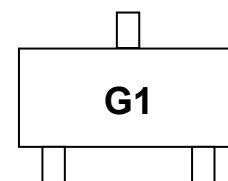
➤ Pin configuration



SOT-23



Circuit Diagram



Marking(Top View)



➤ **Absolute Maximum Ratings**($T_A=25^{\circ}\text{C}$ unless otherwise noted)

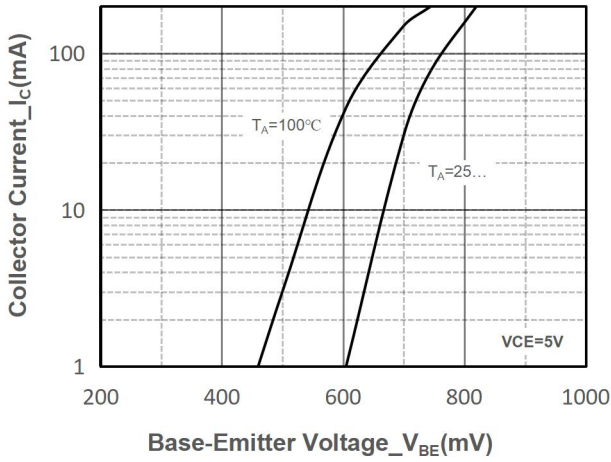
Parameter	Symbol	Value	Unit
Collector-Base Voltage	V_{CB0}	180	V
Collector- Emitter Voltage	V_{CE0}	160	V
Emitter-Base Voltage	V_{EB0}	6	V
Collector Current-Continuous	I_C	600	mA
Collector Power Dissipation	P_C	625	mW
Junction Temperature	T_J	150	$^{\circ}\text{C}$
Storage Temperature	T_{STG}	-55 to 150	$^{\circ}\text{C}$

➤ **Electrical Characteristics** ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

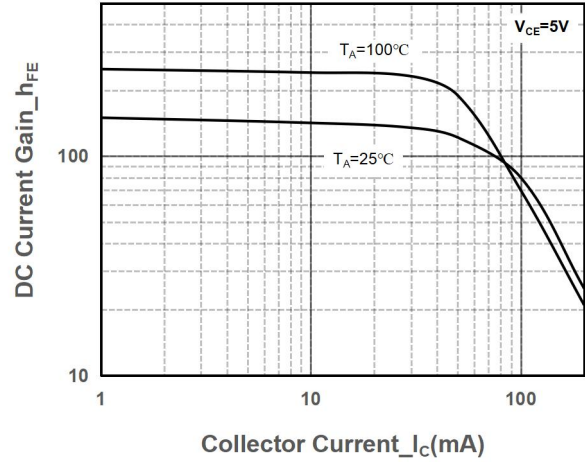
Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Collector-Base Breakdown Voltage	BV_{CB0}	$I_C=0.1\text{mA}, I_E=0$	180			V
Collector-emitter Breakdown Voltage	BV_{CE0}	$I_C=1\text{mA}, I_B=0$	160			V
Emitter -Base Breakdown Voltage	BV_{EB0}	$I_E=0.1\text{mA}, I_C=0$	6			V
Collector Cutoff Current	I_{CB0}	$V_{CB}=120\text{V}, I_E=0$			0.05	μA
Emitter Cutoff Current	I_{EB0}	$V_{EB}=4\text{V}, I_C=0$			0.05	μA
DC Current Gain	h_{FE}	$V_{CE}=5\text{V}, I_C=10\text{mA}$	100		300	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=50\text{mA}, I_B=5\text{mA}$			0.5	V
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=50\text{mA}, I_B=5\text{mA}$			1.0	V
Transition frequency	f_T	$V_{CE}=5\text{V}, I_C=10\text{mA}$ $f=30\text{MHz}$	100		300	MHz



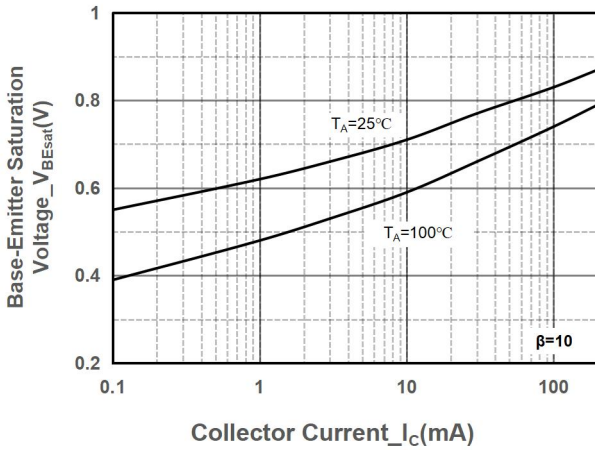
➤ **Typical Performance Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)**



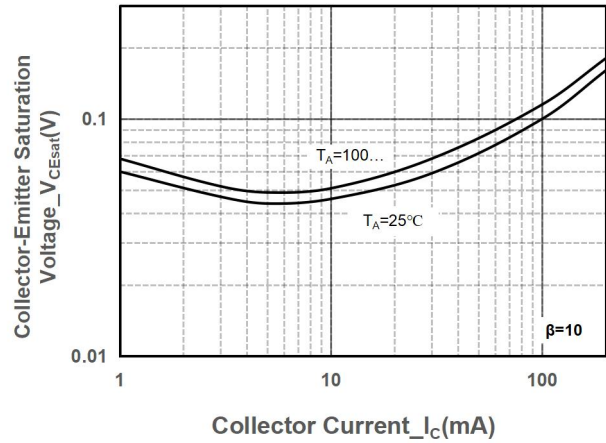
Collector Current vs. Base-Emitter Voltage



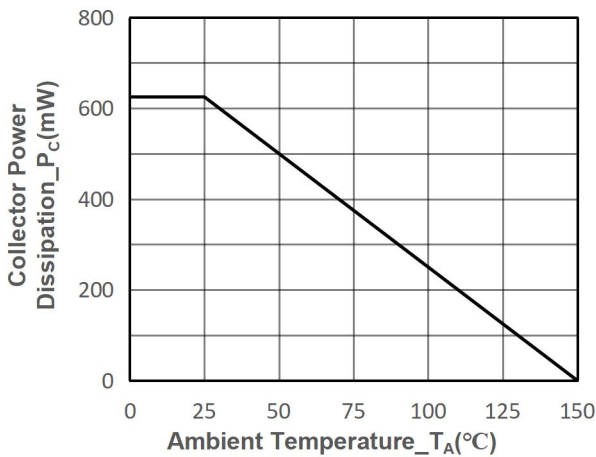
DC Current Gain vs. Collector Current



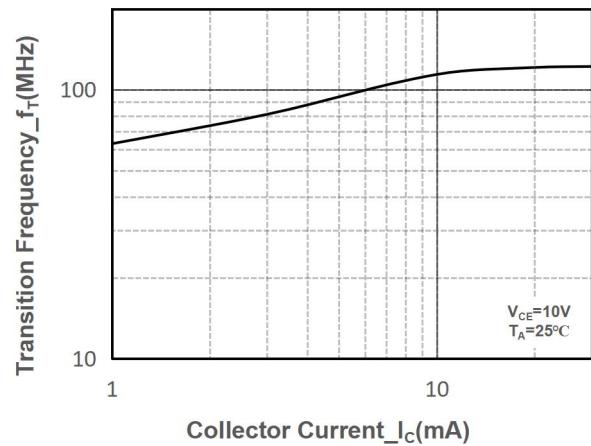
$V_{BE(sat)}$ vs. Collector Current



$V_{CE(sat)}$ vs. Collector Current



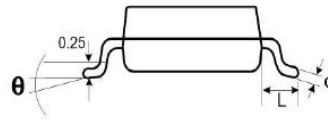
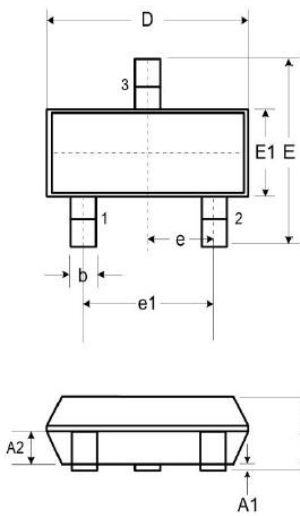
Power derating vs. Ambient temperature



Transition Frequency vs. Collector Current

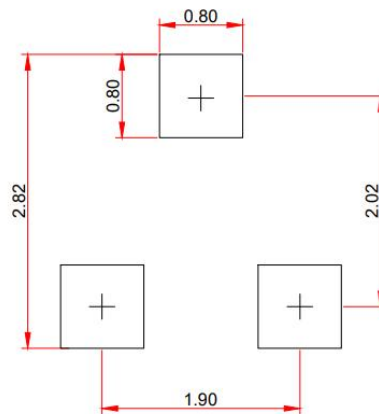


● Package Information



DIM	Millimeters		
	Min.	Typ.	Max.
A	0.89	-	1.12
A1	0.01	-	0.10
A2	0.88	0.95	1.02
b	0.30	-	0.51
c	0.08	-	0.18
D	2.80	2.90	3.04
E	2.10	2.37	2.64
E1	1.20	1.30	1.40
e1	1.90		
e	0.95		
L	0.40	0.50	0.60
L1	0.55		
N	3		
θ	0°	-	8°

Recommended Pad outline(Unit: mm)





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